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Attorney Docket No. 0756-7272

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: ) Group Art Unit: 2811  
Hongyong ZHANG et al. ) Examiner:  
Serial No. 10/808,353 )  
Filed: March 25, 2004 )  
For: SEMICONDUCTOR DEVICE AND )  
METHOD FOR ITS PREPARATION )  
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                            ) I hereby certify that this correspondence is  
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REQUEST FOR CORRECTED PTO 1449 FORM

Honorable Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

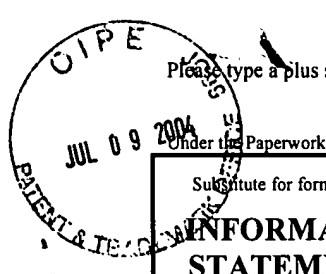
Sir:

It has come to the attention of Applicant that the two of the articles listed on the PTO 1449 Form accompanying the Information Disclosure Statement filed March 25, 2004 need be revised to include further information. Specifically, Volume 60, No. 2, pages 225-227, should be added to the citation for the article entitled *In Situ Transmission Electron Microscopy Studies of Silicide-Mediated Crystallization of Amorphous Silicon*, and pages 8279-8289 should be added to the citation of the article entitled *Silicide Formation and Silicide-Mediated Crystallization of Nickel-Implanted Amorphous Silicon Thin Films*. Therefore, it is respectfully requested that the Examiner line through the erroneous listing on the PTO 1449 filed March 25, 2004, and evidence his consideration of the above-mentioned articles by initialing the attached PTO 1449 Form.

Respectfully submitted,

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PTO/SB/08A (08-00)

Approved for use through 10/31/2002. OMB 0651-0031

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Substitute for form 1449A/PTO

## **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

(use as many sheets as necessary)

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***Complete if Known***

Application Number	10/808,353
Filing Date	March 25, 2004
First Named Inventor	Hongyong ZHANG, et al.
Group Art Unit	2811
Examiner Name	
Attorney Docket Number	0756-7272

## U.S. PATENT DOCUMENTS

## FOREIGN PATENT DOCUMENTS

Examiner Initials\* Cite No.<sup>1</sup> Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s) publisher, city and/or country where published.

T<sup>2</sup>

C. Hayzelden et al., "In Situ Transmission Electron Microscopy Studies of Silicide-Mediated Crystallization of Amorphous Silicon," Volume 60, No. 2, Pages 225-227

Hayzelden et al., "Silicide Formation and Silicide-Mediated Crystallization of Nickel-Implanted Amorphous Silicon Thin Films," J. Appl. Phys., Vol. 73, No. 12, 15 June 1993, Pages 8279-8289.

Examiner Signature		Date Considered	
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<sup>1</sup> Unique citation designation number. <sup>2</sup> See attached Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial

With your kind permission, I would like to forward the attached letter to the ISEF office.

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